

Form PTO-1449

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.
37392SERIAL NO.
10/521,879INFORMATION DISCLOSURE CITATION
BY APPLICANT
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Fabrice Pardo et al.FILING DATE:
January 21, 2005GROUP ART UNIT:
2814

U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
JCI	A	5,227,648	07/1993	Woo			
JCI	B	5,663,639	09/1997	Brown et al.			
	C						
	D						
	E						

FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Class	Subclass	Translation
JCI	F	0 651 448 A1	03/1995	European			Corresponds to U.S. Patent No.: 5,512,763
	G	2 803 950	07/2001	France			Corresponds to U.S. Publication No.: 2003/010979
	H						

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

JCI	I	Katsumi Kishino et al., "Resonant Cavity-Enhanced (RCE) Photodetectors, August 8, 2001, pages 2025 - 2034,
JCI	J	Wolfgang Kowalsky et al., "High Bandwidth Metal-Semiconductor-Metal Photodiodes with Integrated Fabry-Perot Resonator for WDM Receivers", August 1992, Pages 214 - 216
JCI	K	A. Strittmatter et al., "High-Speed, High Efficiency Resonant-Cavity Enhanced InGaAs MSM Photodetectors", Pages 1231- 1232
JCI	L	A. Strittmatter et al., "High-Frequency , Long-Wavelength Resonant-Cavity-Enhanced InGaAs MSM Photodetectors", September 15, 1996, Pages 145 - 148

Examiner: **/John Ingham/**Date Considered **08/14/2006**

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Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.